

TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

SSM6K411TU

○ Power Management Switch Applications

○ High-Speed Switching Applications

- 2.5-V drive
- Low ON-resistance : $R_{DS(ON)} = 23.8 \text{ m}\Omega$ (max) (@ $V_{GS} = 2.5 \text{ V}$)
 $R_{DS(ON)} = 14.3 \text{ m}\Omega$ (max) (@ $V_{GS} = 3.5 \text{ V}$)
 $R_{DS(ON)} = 12 \text{ m}\Omega$ (max) (@ $V_{GS} = 4.5 \text{ V}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristic	Symbol	Rating	Unit
Drain-Source voltage	V_{DSS}	20	V
Gate-Source voltage	V_{GSS}	± 12	V
Drain current	DC	I_D (Note1)	A
	Pulse	I_{DP} (Note1)	
Power dissipation	P_D (Note2)	1	W
	$t < 10\text{s}$	2	
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to 150	$^\circ\text{C}$

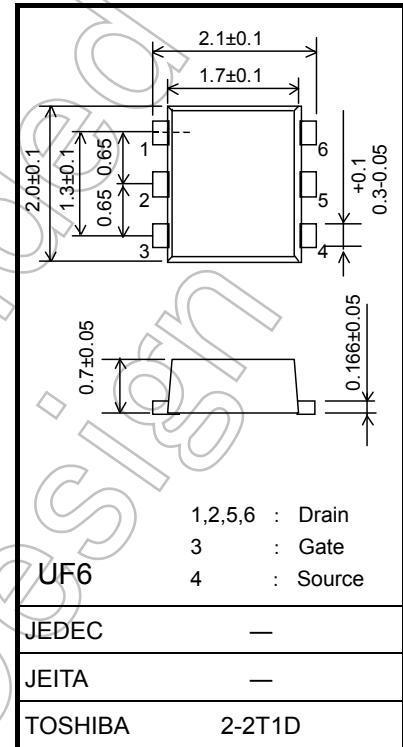
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: The channel temperature should not exceed 150°C during use.

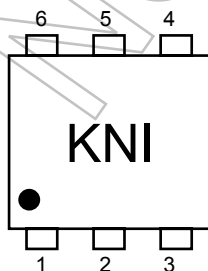
Note 2: Mounted on an FR4 board. ($25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}$, Cu Pad: 645 mm^2)

Unit: mm

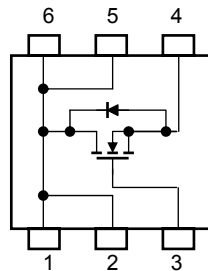


Weight: 7.0 mg (typ.)

Marking



Equivalent Circuit (top view)



Start of commercial production
2010-05

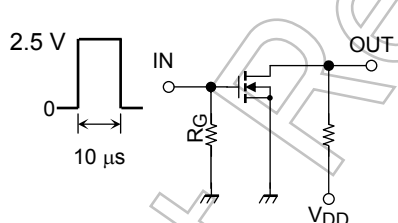
Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-Source breakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	20	—	—	V
	V (BR) DSX	I _D = 10 mA, V _{GS} = -12 V	8	—	—	
Drain cut-off current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V	—	—	10	μA
Gate leakage current	I _{GSS}	V _{GS} = ±12 V, V _{DS} = 0 V	—	—	±0.1	μA
Gate threshold voltage	V _{th}	V _{DS} = 3 V, I _D = 1 mA	0.5	—	1.2	V
Forward transfer admittance	Y _{fs}	V _{DS} = 3 V, I _D = 2.0 A (Note 3)	6.5	13	—	S
Drain-source ON-resistance	R _{DS} (ON)	I _D = 7.0 A, V _{GS} = 4.5 V (Note 3)	—	8.7	12	mΩ
		I _D = 6.0 A, V _{GS} = 3.5 V (Note 3)	—	10.5	14.3	
		I _D = 4.0 A, V _{GS} = 2.5 V (Note 3)	—	15.5	23.8	
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	—	710	—	pF
Output capacitance	C _{oss}		—	240	—	
Reverse transfer capacitance	C _{rss}		—	170	—	
Total Gate Charge	Q _g	V _{DD} = 10 V, I _D = 10 A V _{GS} = 4.5 V	—	9.4	—	nC
Gate-Source Charge	Q _{gs1}		—	1.9	—	
Gate-Drain Charge	Q _{gd}		—	4.1	—	
Switching time	Turn-on time	V _{DD} = 10 V, I _D = 2 A V _{GS} = 0 to 2.5 V, R _G = 4.7 Ω	—	32	—	ns
	Turn-off time		—	23	—	
Drain-Source forward voltage	V _{DSF}	I _D = -10 A, V _{GS} = 0 V (Note 3)	—	-0.8	-1.2	V

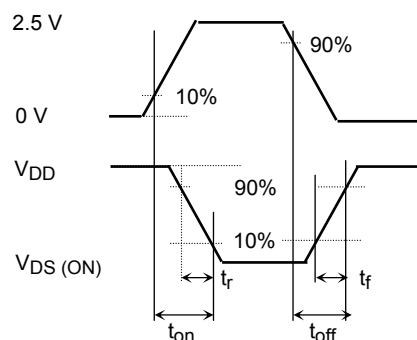
Note 3: Pulse test

Switching Time Test Circuit

(a) Test Circuit



V_{DD} = 10 V
R_G = 4.7 Ω
Duty ≤ 1%
V_{IN}: t_r, t_f < 5 ns
Common Source
Ta = 25°C

(b) V_{IN}(c) V_{OUT}

Notice on Usage

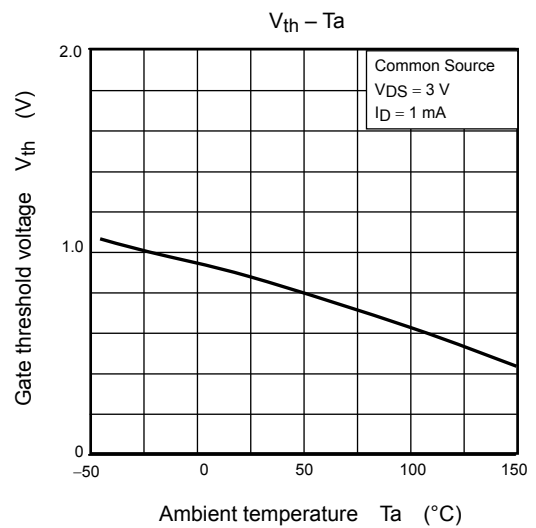
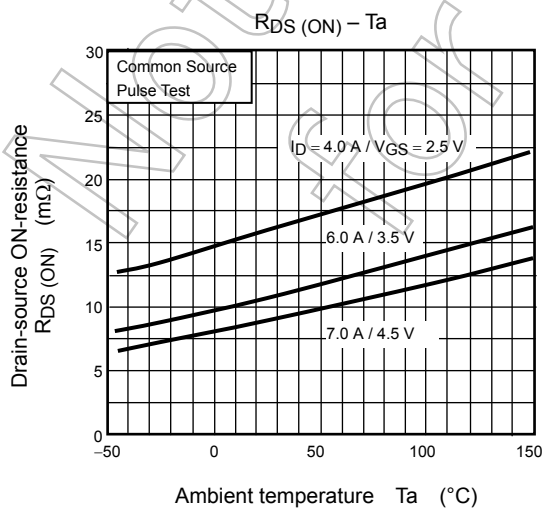
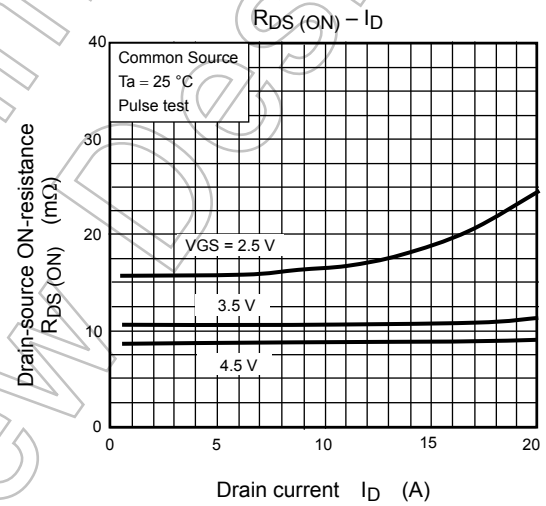
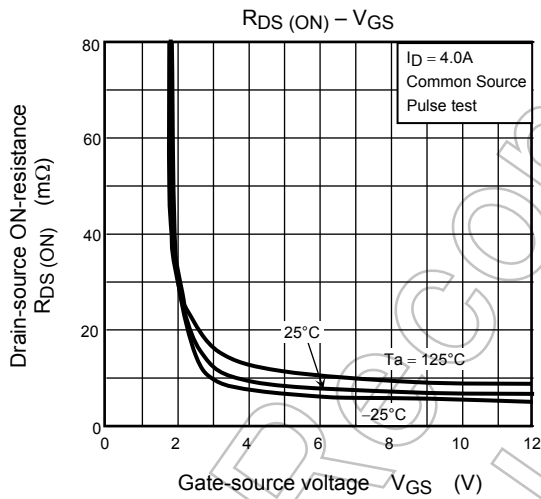
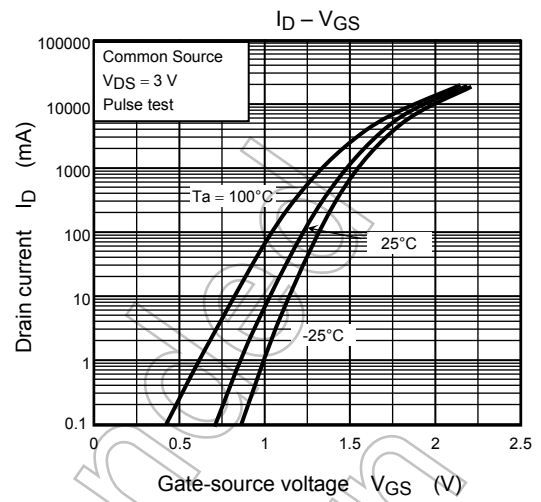
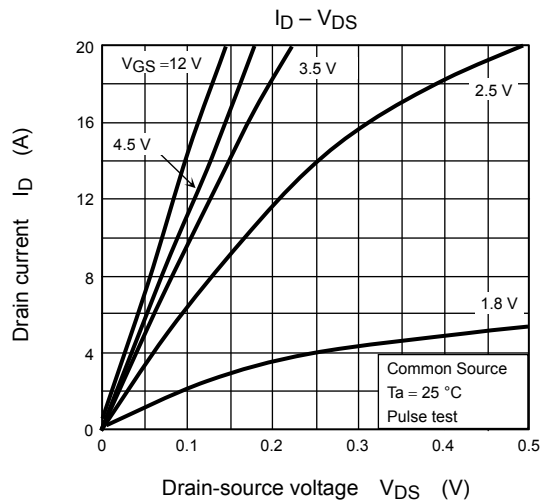
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to be low (1 mA for the SSM6K411TU). Then, for normal switching operation, V_{GS(on)} must be higher than V_{th}, and V_{GS(off)} must be lower than V_{th}. This relationship can be expressed as: V_{GS(off)} < V_{th} < V_{GS(on)}.

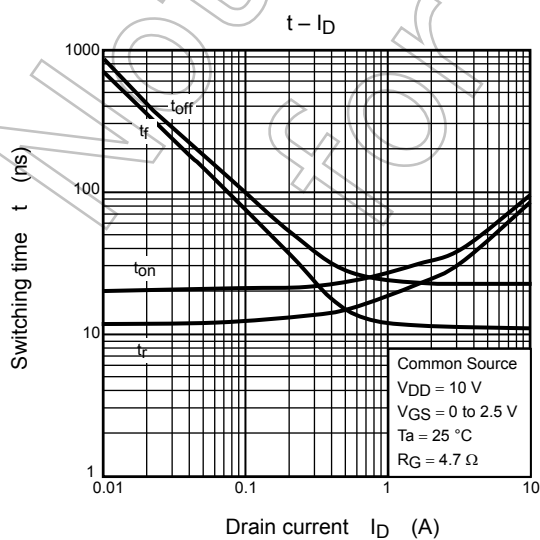
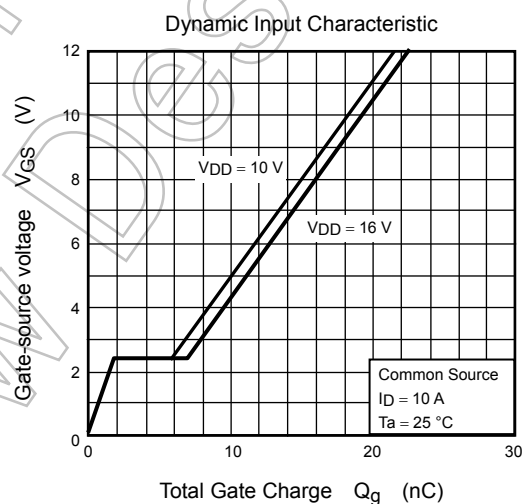
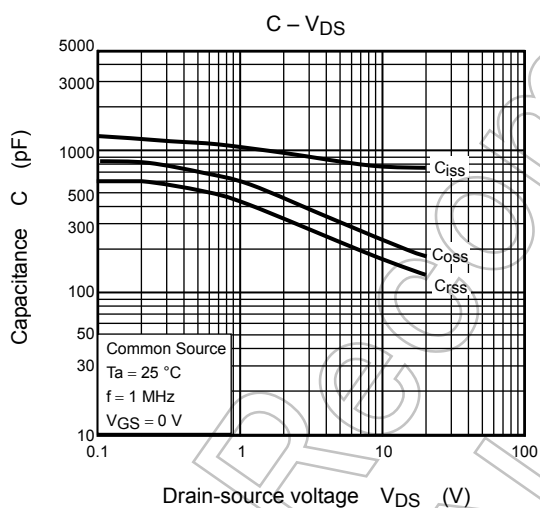
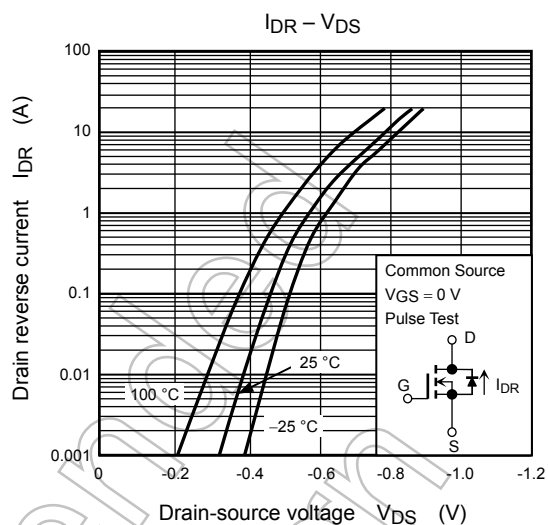
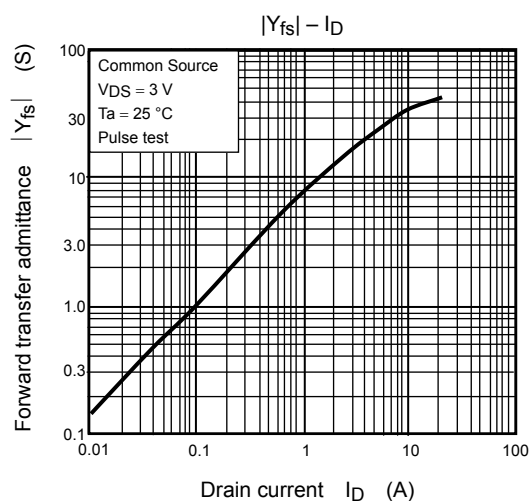
Take this into consideration when using the device.

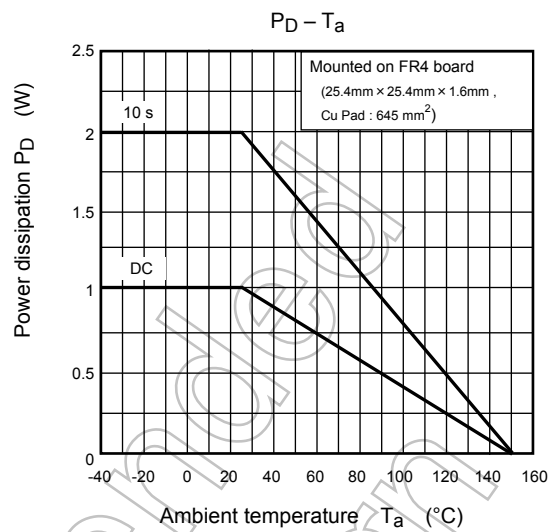
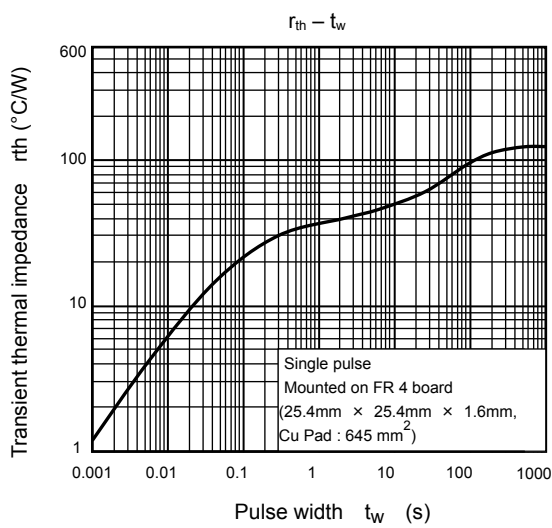
Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance R_{th (ch-a)} and power dissipation P_D vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.







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